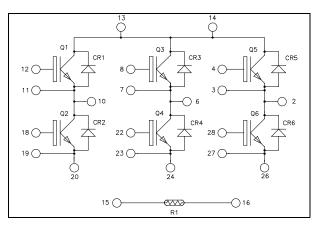
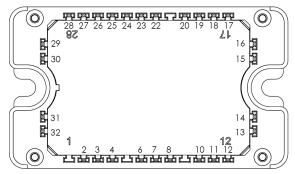
Triple phase leg High speed IGBT 5 Power Module

 $V_{CES} = 650V$; $I_C = 50A$ @ Tc = 25°C





Pins 20, 24 & 26 must be shorted together to perform a 3 phase bridge.

Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- High speed IGBT 5
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 100 kHz
 - Low leakage current
- Very low stray inductance
- Kelvin source for easy drive
- Internal thermistor for temperature monitoring

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS Compliant

All ratings @ $T_i = 25$ °C unless otherwise specified

Absolute maximum ratings (Per IGBT)

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Voltage		650	V
Ţ	Continuous Collector Current	$T_C = 25^{\circ}C$	50	
I_{C}	Continuous Collector Current T_0	$T_C = 80$ °C	30	Α
I_{CM}	Pulsed Collector Current	$T_C = 25^{\circ}C$	100	
V_{GE}	Gate – Emitter Voltage		±20	V
P_{D}	Power Dissipation		125	W

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handing Procedures Should Be Followed.

Electrical	Characteristics	(per IGBT)
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Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit	
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 650V$				50	μΑ
V	Collector Emitter Saturation Voltage	$V_{GE} = 15V$	$T_j = 25^{\circ}C$		1.65	2.2	V
$V_{CE(sat)}$	Conector Emitter Saturation Voltage	$I_{\rm C} = 50 {\rm A}$ $T_{\rm j} = 150$	$T_{j} = 150^{\circ}C$		1.9		v
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 0.5 \text{mA}$		3.3	4.0	4.7	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V$, $V_{CE} = 0V$				120	nA

Dynamic Characteristics (per IGBT)

•	Characteristic	Test Condition	is	Min	Typ	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$			3000		
Coes	Output Capacitance	$V_{CE} = 25V$ $f = 1MHz$			50		pF
C_{res}	Reverse Transfer Capacitance				11		
Q_{G}	Gate charge	$V_{GE} = 15V, I_{C} = V_{CE} = 520V$	= 50A		120		nC
$T_{d(on)}$	Turn-on Delay Time	Inductive Swit	ching (25°C)		21		
$T_{\rm r}$	Rise Time	$V_{GE} = 15V$			15		
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 400V$ $I_{\text{C}} = 25A$			180		ns
$T_{\rm f}$	Fall Time	$R_G = 12\Omega$			18		ı
$T_{d(on)}$	Turn-on Delay Time	Inductive Swit	ching (150°C)		20		
T_{r}	Rise Time	$V_{GE} = 15V$ $V_{Bus} = 400V$ $I_{C} = 25A$ $R_{G} = 12\Omega$		15		ļ	
T _{d(off)}	Turn-off Delay Time				205		ns
T_{f}	Fall Time		_			26	
Eon	Turn on Energy	$V_{GE} = 15V$ $V_{Bus} = 400V$	$T_j = 150$ °C		0.75		I
E _{off}	Turn off Energy	$I_C = 25A$ $R_G = 12\Omega$	$T_j = 150$ °C		0.3		mJ
R_{thJC}	Junction to Case Thermal Resistance					1.2	°C/W

Diode ratings and characteristics (per diode) Symbol Characteristic Te

Symbol	Characteristic Test Conditions		Min	Тур	Max	Unit	
V_{RRM}	Peak Repetitive Reverse Voltage					650	V
I_{RM}	Reverse Leakage Current	$V_R=650V$				50	μΑ
I_F	DC Forward Current		$Tc = 25^{\circ}C$		50		A
V	Diada Famuand Valtaga	$I_F = 50A$	$T_i = 25^{\circ}C$		1.6	2.2	V
V_{F}	Diode Forward Voltage	$I_F = 50A$ $V_{GE} = 0V$	$T_{i} = 150^{\circ}C$		1.65		V
t_{rr}	Reverse Recovery Time		$T_j = 25^{\circ}C$		46		ns
L _{TT}	Reverse Recovery Time	$I_F = 25A$ $V_R = 400V$ $T_j = 150^{\circ}C$		62		113	
		$di/dt = 1500A/\mu s$	$T_j = 25^{\circ}C$		0.5		C
Q_{rr}			$T_{\rm j} = 150^{\circ}{\rm C}$		1		μC
R_{thJC}	Junction to Case Thermal Resistance					1.4	°C/W



i ower matters.

Temperature sensor NTC (see application note APT0406 on www.microsemi.com).

Symbol	Characteristic		Min	Тур	Max	Unit
R ₂₅	Resistance @ 25°C	stance @ 25°C		50		kΩ
$\Delta R_{25}/R_{25}$				5		%
$B_{25/85}$	$T_{25} = 298.15 \text{ K}$			3952		K
$\Delta \mathrm{B/B}$		T _C =100°C		4		%

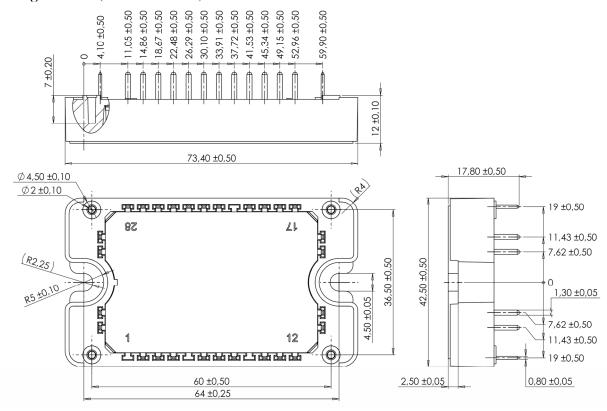
$$R_T = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature}$$

$$R_T: \text{ Thermistor value at T}$$

Package characteristics

Symbol	Characteristic			Min	Max	Unit
V_{ISOL}	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz			4000		V
T_{J}	Operating junction temperature range			-40	175	
T_{JOP}	Recommended junction temperature under switching conditions			-40	T _J max -25	°C
T_{STG}	Storage Temperature Range			-40	125	
$T_{\rm C}$	Operating Case Temperature			-40	125	
Torque	Mounting torque	To heatsink	M4	2	3	N.m
Wt	Package Weight	•			110	g

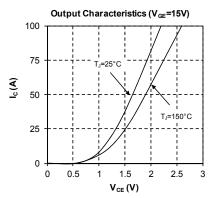
Package outline (dimensions in mm)

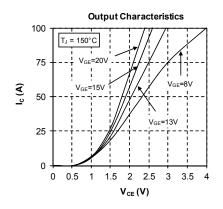


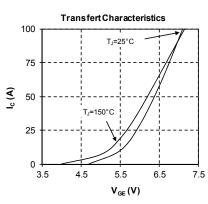
See application note 1906 - Mounting Instructions for SP3F Power Modules on www.microsemi.com

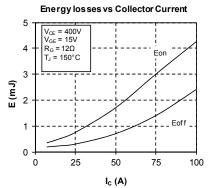


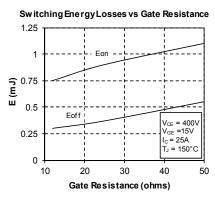
Typical Performance Curve

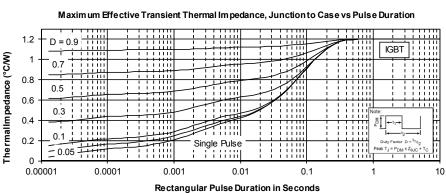






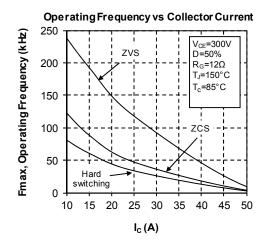


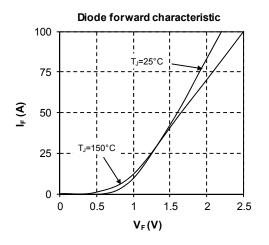


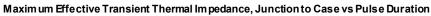


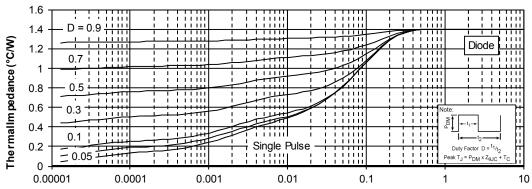


Power Matters.™









Rectangular Pulse Duration in Seconds



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